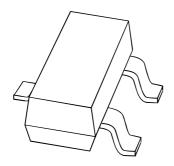
DISCRETE SEMICONDUCTORS

DATA SHEET



BAV170Low-leakage double diode

Product data sheet Supersedes data of 1999 May 11 2003 Mar 25



Low-leakage double diode

BAV170

FEATURES

- Plastic SMD package
- Low leakage current: typ. 3 pA
- Switching time: typ. 0.8 μs
- Continuous reverse voltage: max. 75 V
- Repetitive peak reverse voltage: max. 85 V
- Repetitive peak forward current: max. 500 mA.

APPLICATION

• Low-leakage current applications in surface mounted circuits.

MARKING

TYPE NUMBER	MARKING CODE ⁽¹⁾	
BAV170	JX*	

Note

1. * = p : Made in Hong Kong.

* = t : Made in Malaysia.

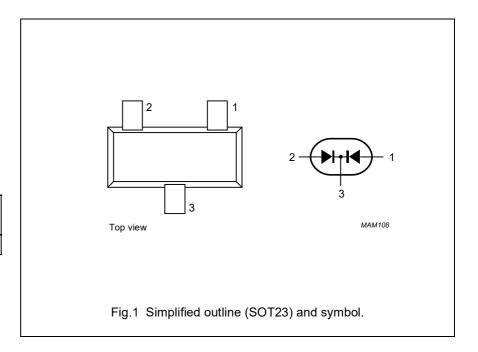
* = W : Made in China.

DESCRIPTION

Epitaxial, medium-speed switching, double diode in a small SOT23 plastic SMD package. The diodes are in common cathode configuration.

PINNING

PIN	DESCRIPTION
1	anode
2	anode
3	common cathode



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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER CONDITIONS		MIN.	MAX.	UNIT
Per diode			•		
V_{RRM}	repetitive peak reverse voltage		_	85	V
V _R	continuous reverse voltage		-	75	V
I _F	continuous forward current	single diode loaded; note 1; see Fig.2	-	215	mA
		double diode loaded; note 1; see Fig.2	-	125	mA
I _{FRM}	repetitive peak forward current		-	500	mA
I _{FSM}	non-repetitive peak forward current	square wave; T _j = 25 °C prior to surge; see Fig.4			
		t _p = 1 μs	_	4	Α
		t _p = 1 ms	_	1	Α
		t _p = 1 s	_	0.5	Α
P _{tot}	total power dissipation	T _{amb} = 25 °C; note 1	-	250	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C

Note

ELECTRICAL CHARACTERISTICS

 T_i = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
Per diode					•
V _F	forward voltage	see Fig.3			
		I _F = 1 mA	_	900	mV
		I _F = 10 mA	_	1000	mV
		I _F = 50 mA	-	1100	mV
		I _F = 150 mA	-	1250	mV
I _R	reverse current	see Fig.5			
		V _R = 75 V	0.003	5	nA
		V _R = 75 V; T _j = 150 °C	3	80	nA
C_d	diode capacitance	f = 1 MHz; V _R = 0; see Fig.6	2	_	pF
t _{rr}	reverse recovery time	when switched from I_F = 10 mA to I_R = 10 mA; R_L = 100 Ω ; measured at I_R = 1 mA; see Fig.7	0.8	3	μs

^{1.} Device mounted on a FR4 printed-circuit board.

Low-leakage double diode

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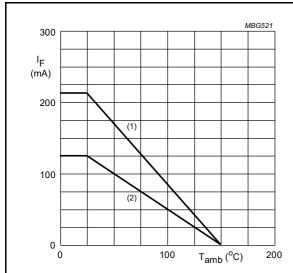
THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-tp}	thermal resistance from junction to tie-point		360	K/W
R _{th j-a}	thermal resistance from junction to ambient	note 1	500	K/W

Note

1. Device mounted on a FR4 printed-circuit board.

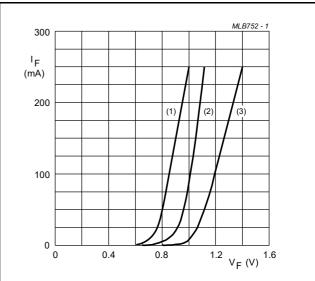
GRAPHICAL DATA



Device mounted on a FR4 printed-circuit board.

- (1) Single diode loaded.
- (2) Double diode loaded.

Fig.2 Maximum permissible continuous forward current as a function of ambient temperature.



- (1) $T_j = 150$ °C; typical values.
- (2) $T_j = 25$ °C; typical values.
- (3) $T_j = 25$ °C; maximum values.

Fig.3 Forward current as a function of forward voltage; per diode.

Low-leakage double diode

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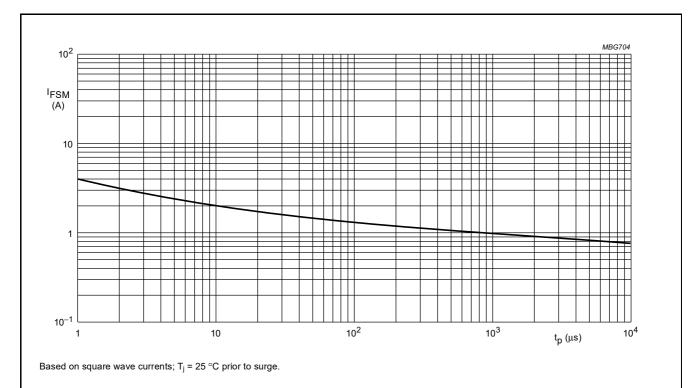
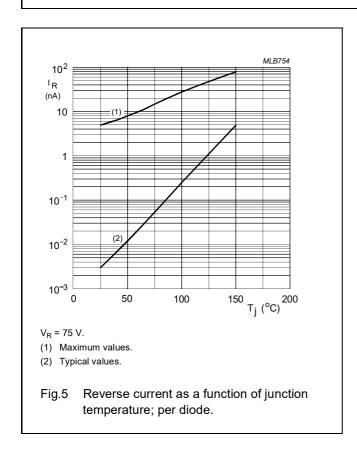
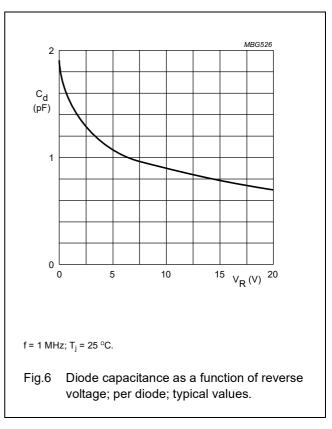


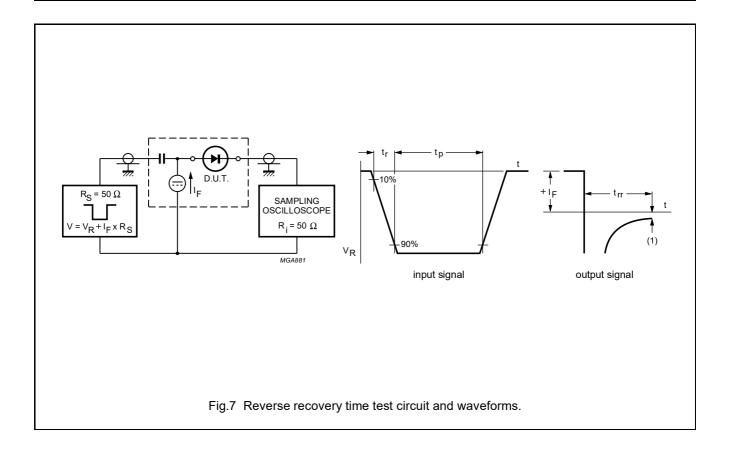
Fig.4 Maximum permissible non-repetitive peak forward current as a function of pulse duration per diode.





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PACKAGE OUTLINE

UNIT

mm

max.

0.48

0.38

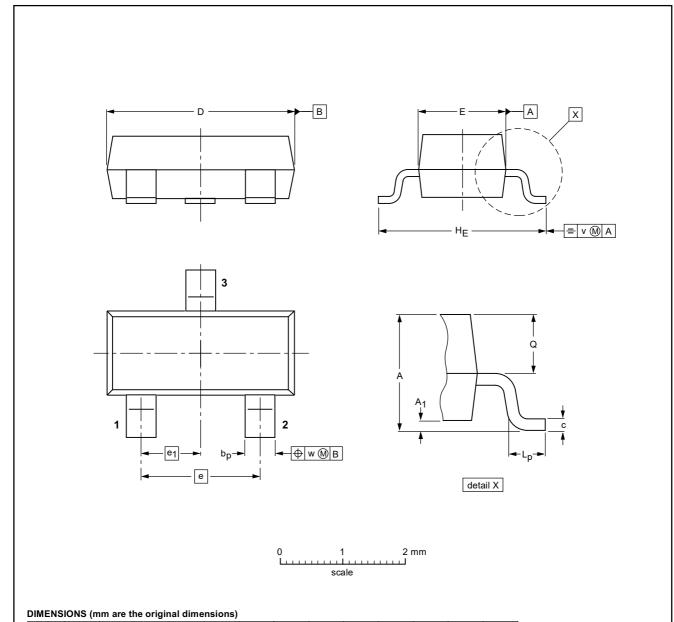
0.15

0.09

1.1

Plastic surface mounted package; 3 leads

SOT23



OUTLINE	NE REFERENCE		REFERENCES		EUROPEAN	ICCUE DATE
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT23		TO-236AB				97-02-28 99-09-13

HE

 L_p

0.45

Q

0.55

0.1

Е

1.9

Low-leakage double diode

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DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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- 2. The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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2003 Mar 25

NXP Semiconductors

Customer notification

This data sheet was changed to reflect the new company name NXP Semiconductors. No changes were made to the content, except for the legal definitions and disclaimers.

Contact information

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